Docket No.

248575US2RD/hc

IN THE UNITED STA

IN RE APPLICATION OF: Izumi HIRANO, et al.

SERIAL NO:

10/772,373

GAU:

FILED:

February 6, 2004

EXAMINER:

ND TRADEMARK OFFICE

FOR:

SEMICONDUCTOR DEVICE AND METHOD OF MANUFACTURING THE SAME

INFORMATION DISCLOSURE STATEMENT UNDER 37 CFR 1.97

COMMISSIONER FOR PATENTS ALEXANDRIA, VIRGINIA 22313

Applicant(s) wish to disclose the following information.

REFERENCES

- The applicant(s) wish to make of record the references listed on the attached form PTO-1449. Copies of the listed references are attached, where required, as are either statements of relevancy or any readily available English translations of pertinent portions of any non-English language references.
- ☐ A check or credit card payment form is attached in the amount required under 37 CFR §1.17(p).

RELATED CASES

- ☐ Attached is a list of applicant's pending application(s) or issued patent(s) which may be related to the present application. A copy of the patent(s), together with a copy of the claims and drawings of the pending application(s) is attached along with PTO 1449.
- A check or credit card payment form is attached in the amount required under 37 CFR §1.17(p).

CERTIFICATION

- ☐ Each item of information contained in this information disclosure statement was first cited in any communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this statement.
- □ No item of information contained in this information disclosure statement was cited in a communication from a foreign patent office in a counterpart foreign application or, to the knowledge of the undersigned, having made reasonable inquiry, was known to any individual designated in 37 CFR §1.56(c) more than three months prior to the filing of this statement.

DEPOSIT ACCOUNT

Please charge any additional fees for the papers being filed herewith and for which no check or credit card payment is enclosed herewith, or credit any overpayment to deposit account number 15-0030. A duplicate copy of this sheet is enclosed.

Respectfully submitted,

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STATEMENT OF RELEVANCY

Reference AA (US 6,020,243) on Form PTO-1449:

This reference discloses a similar inclined composition of Hf (Zr) SiON layer, but Hf (Zr) concentration is not low near the interface with gate electrode.

Form PTO 1449		U.S. DEPARTMENT	OF COMMERCE				RIAL NO.	
(Modified) PATENT AND TRADEMARK OFFICE				248575US2RD		10/772,373		
		IPE		APPLICANT				
LIST OF	REFEF	RENCES OF BY AP	PLICANT	Izumi HIRANO, et al.				
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EXAMINER		DOCUMENTINAS			-	SUB	EII I	NG DATE
INITIAL		NUMBER	DATE	NAME	CLASS	SS CLASS IF APPROPRIATE		
	AA	6,020,243	02/01/2000	R. M. WALLACE, et al.				
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AZ					Additional References sheet(s) attached			
Examiner					Date Co	e Considered		
*Examiner: I	nitial if	reference is considered	, whether or no	ot citation is in conformance with MPE	P 609; Draw	line through	h citation i	f not in